

内殻素励起によるX線ラマン散乱を用いた 電子構造の研究

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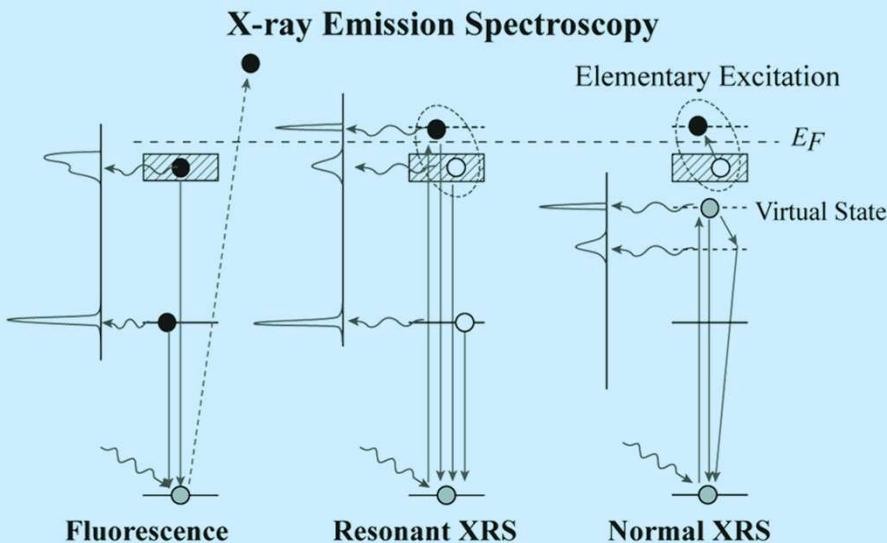
Collaborator

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Background

Experimental



Interaction between electron and radiation

$$H_{int} = \frac{e^2}{2mc^2} A^2 - \frac{e}{mc} (\mathbf{pA})$$

p: momentum of electron

A: vector potential

Kramers-Heisenberg formula (~pA) << RIXS (RXRS) >>

$$\frac{d^2\sigma}{d\Omega_{k_2} d(\hbar\omega)} \sim \sum_j \left| \sum_i \frac{\langle j | T_2 | i \rangle \langle i | T_1 | g \rangle}{E_g + \hbar\Omega - E_i + i\Gamma_i} \right|^2 \delta(E_g + \hbar\Omega - E_j - \hbar\omega)$$

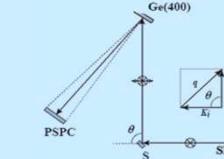
Dynamical structure factor (~A²) << XRS >>

$$\frac{d^2\sigma}{d\Omega_{k_2} d(\hbar\omega)} \sim \frac{\omega}{\Omega} \left(\frac{e^2}{mc^2} \right)^2 (\mathbf{e}_1 \cdot \mathbf{e}_2) S(\mathbf{k}_1 - \mathbf{k}_2, \Omega - \omega)$$

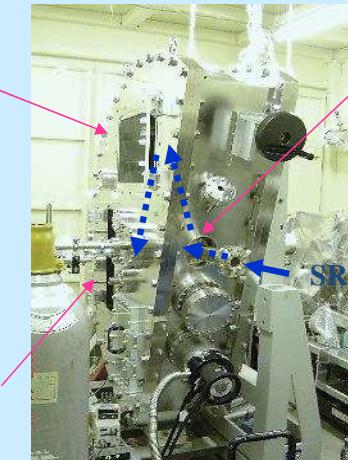
S: Dynamical structure factor

ESCARGOT (X-ray spectrometer) @KEK-PF BL7C, BL15B (bending)

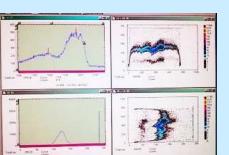
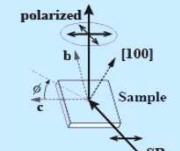
Crystal Ge(400)



Detector (PSPC)



Sample

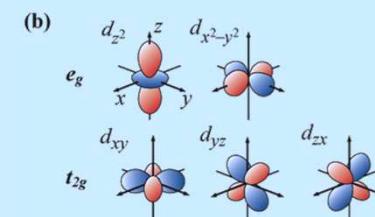
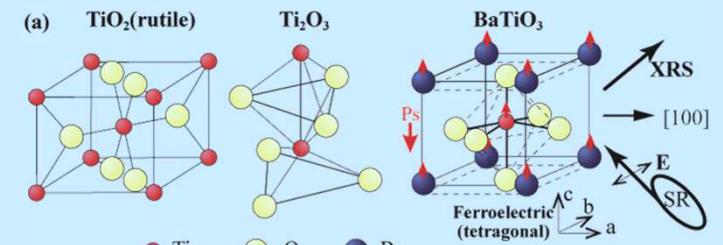


position data

PC

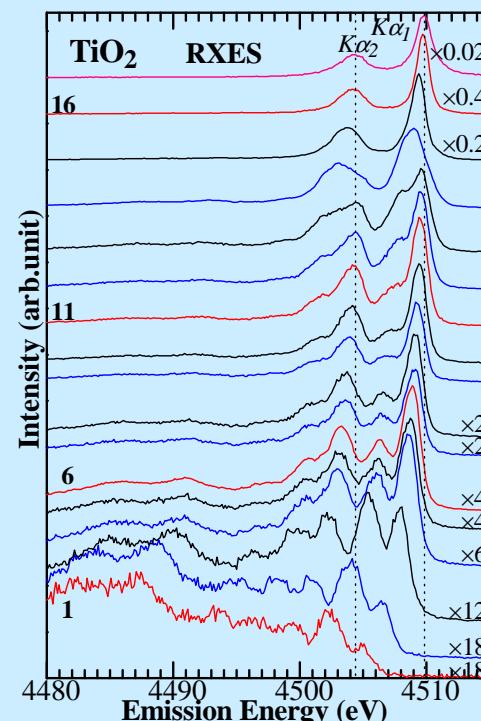
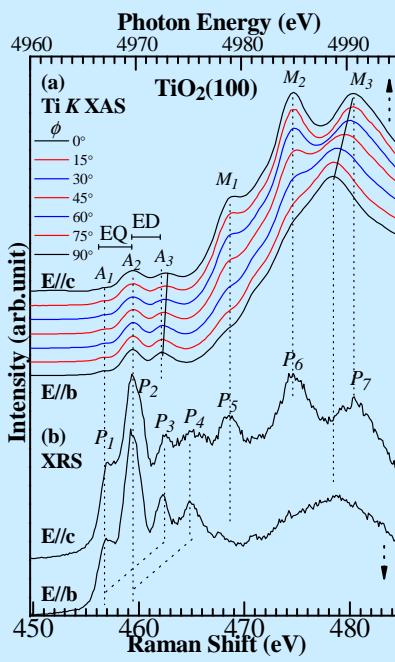
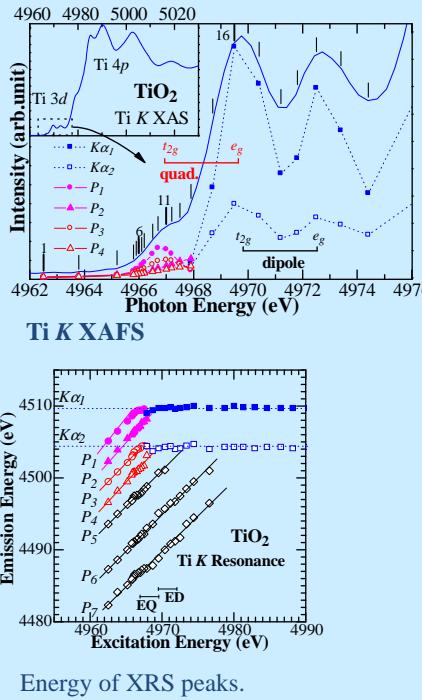
Sample

- TiO₂ (rutile) : powder, single crystal (100)
- Ti₂O₃: powder
- BaTiO₃ (BTO): powder, single crystal (100)

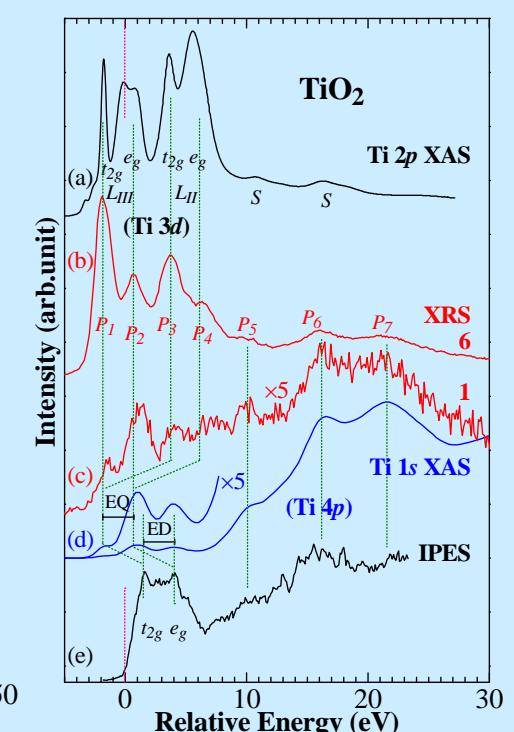
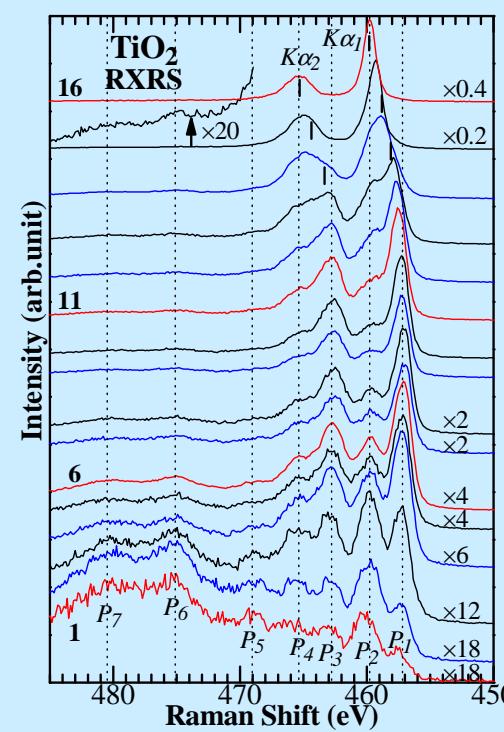


XRS Spectra of TiO_2

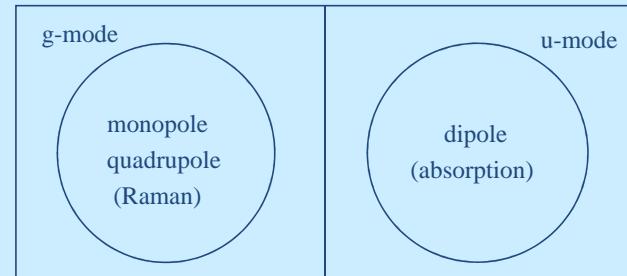
Y. Tezuka, et al., J. Phys. Soc. Jpn. 83, 014707 (2014).



Ti K resonant XES.

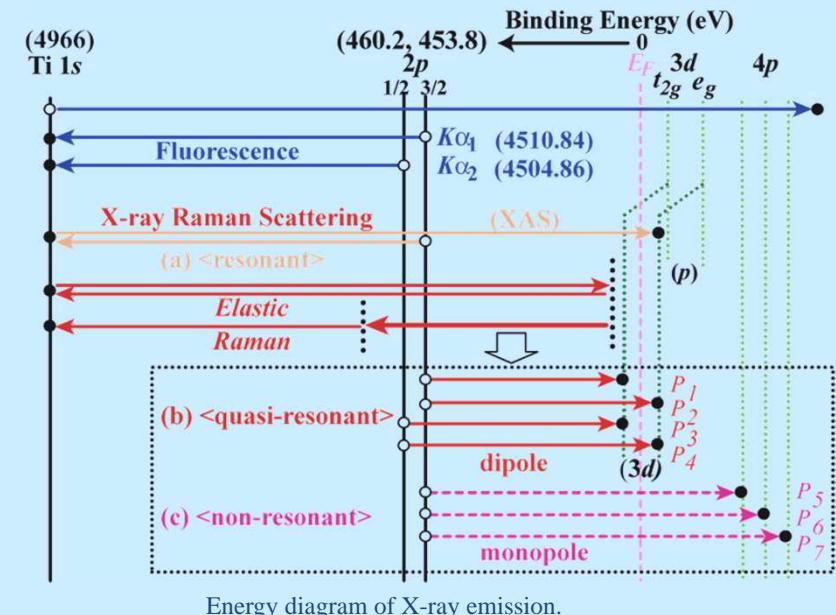


Selection Rule (non-resonant) with inversion symmetry

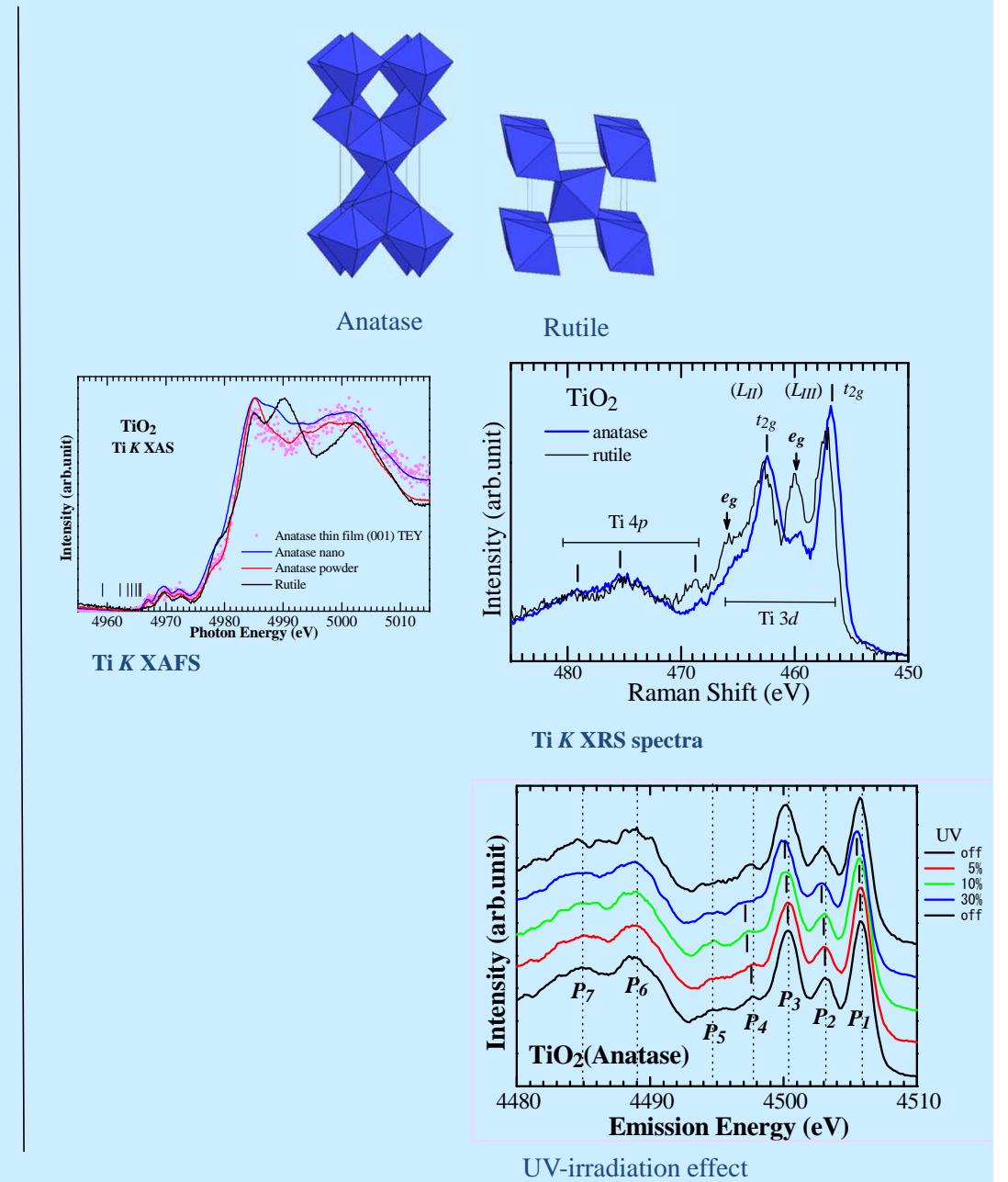
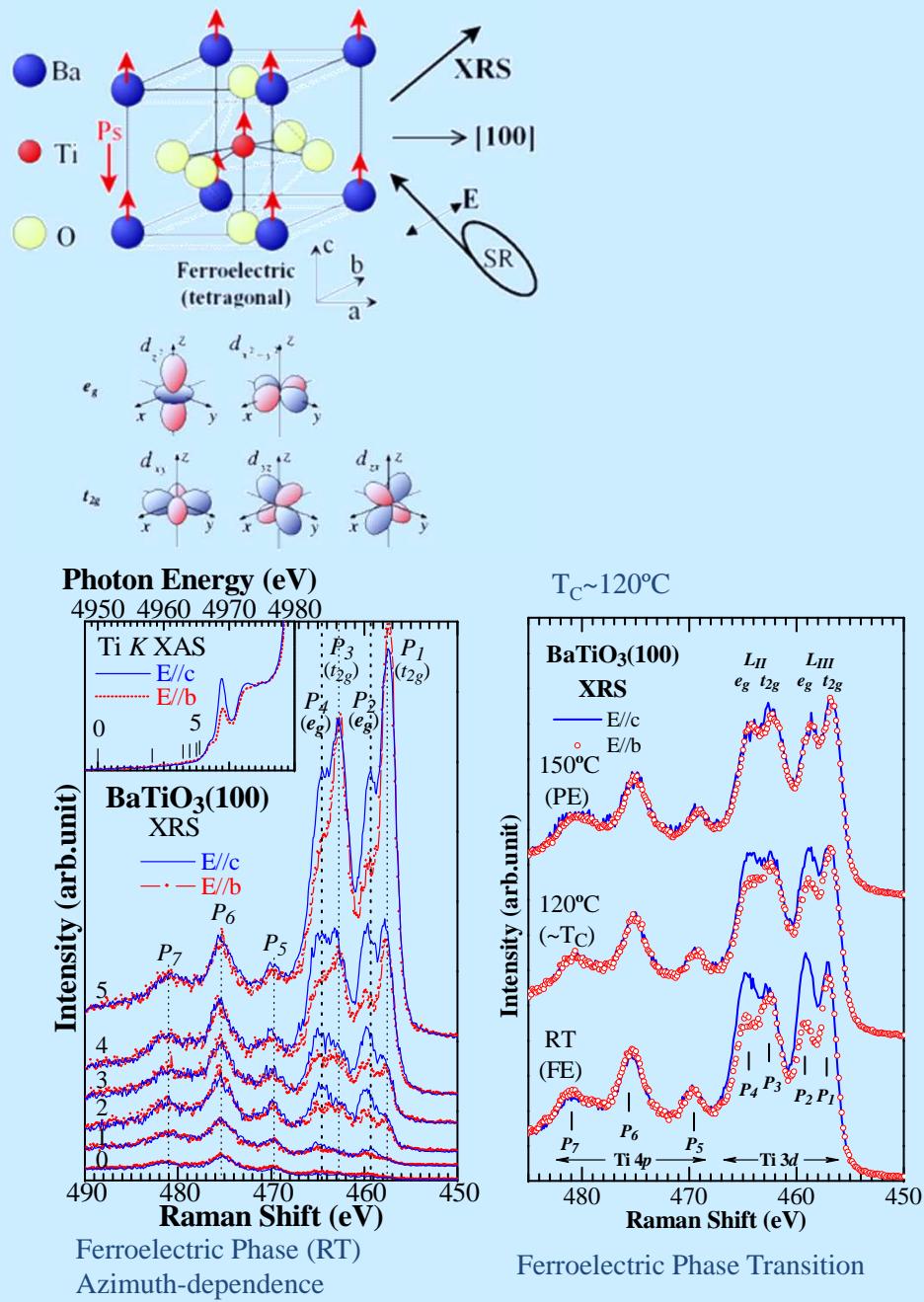


Ligand field splitting

T. Uozumi, et al., Europhys. Lett. 18, 85 (1992).

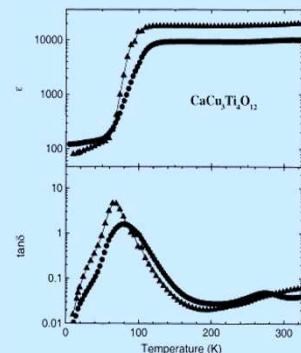
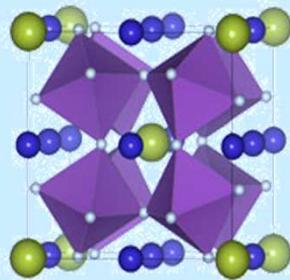


Ferroelectric BaTiO₃ (BTO) / Anatase (TiO₂)

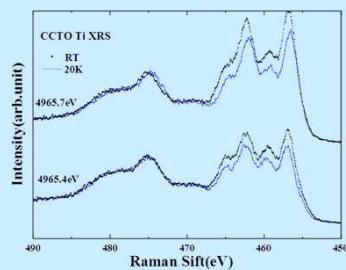
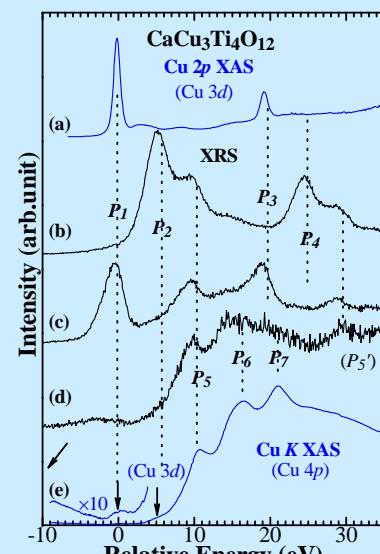
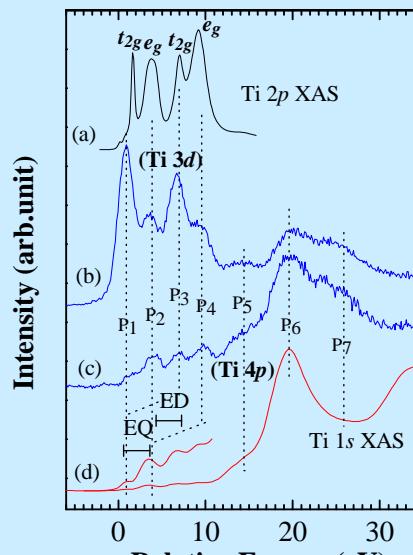


CaCu₃Ti₄O₁₂ (CCTO)

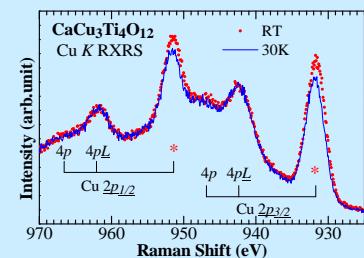
/ CuO



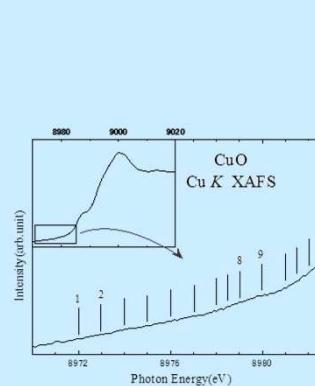
A.P. Ramirez, et al.,
Solid State Commun., **115**, 217 (2000).



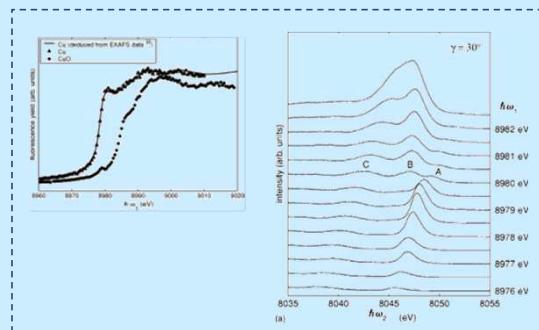
Temperature dependence of XRS
Ti K resonance



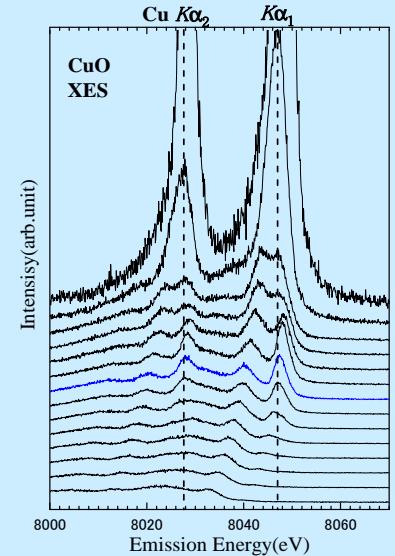
Temperature dependence of XRS
Cu K resonance



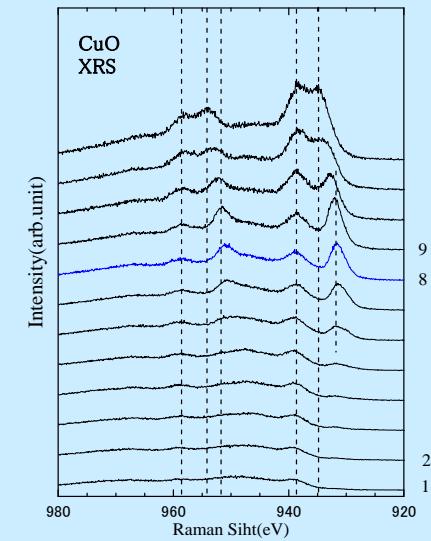
Cu K XAFS



G. Döring, et al., Phys. Rev. B**70**, 085115 (2004).



Cu K resonant XES.



Cu K resonant XRS spectra.

Summary

Other results

- Ti_2O_3
 - Much lifetime broadening
- Anatase TiO_2
 - Photocatalyst
 - More $3d$ electrons than rutile
 - Peak shift by UV-radiation
- Nano-particle Anatase TiO_2
 - Size dependence
 - Much $3d$ -electrons at large (loose → fasten)
 - Dope effect
 - Electron is doped in t_{2g} state
- Steel (Fe)
 - Electronic state change by heat and pressure.

Feature Plans of XRS / XES

X-ray Raman Scattering

- Photon-in/photon-out
 - Bulk sensitive
 - Unnecessary conductivity → Insulator
 - Stable in changed environment → Excited state
 - Time dependence
- Coherent Process
 - Selection rule ~ strict
 - Nonlinear Process
- Joint DOS (Elementary Excitation)
 - Core-excitation → Partial DOS of unoccupied state
 - Mapping (Elements, Excitations)
 - k -dependence

Need High Brilliance !!

X-ray Emission Spectroscopy

- Partial DOS of occupied state